## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

of in re the Application of: KANO et al.

Group Art Unit: 2812

Serial No.: 09/941,982

Examiner: Mulpuri, Savitri

Filed: August 30, 2001

P.T.O. Confirmation No.: 7536

For. METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR LAYER, AND METHOD OF MANUFACTURING NITRIDE-BASED SEMICONDUCTOR DEVICE

## PETITION FOR EXTENSION OF TIME

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Date: May 5, 2004

Sir:

Applicants petition the Commissioner for Patents to extend the time for response to the Office Action dated November 5, 2003 for three months from February 5, 2004 to May 5, 2004.

Attached please find a check in the amount of \$950.00 to cover the cost of the extension. In the event that any additional fees are due in connection with this paper, please charge our Deposit Account No. 50-2866. This paper is filed in triplicate.

Respectfully submitted,

WESTERMAN, HATTORI, DANIELS & ADRIAN, LLP

Stephen G. Adrian Attorney for Applicants Reg. No. 32,878

SGA/arf

Atty. Docket No. **011083**1250 Connecticut Avenue, N.W. Suite 700
Washington, D.C. 20036
(202) 822-1100

35/06/2004 SSESHE1 00000036 09941982

1 FC:1253